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02/19/02

PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10079269	FILING DATE 02/19/2002	CLASS 117	SUBCLASS 8.1	GAU 1765	EXAMINER SUNG J
**APPLICANTS: Hooper Stewart; Barnes Jennifer; Bousquet Valerie; Heffernan Jonathan;					
**CONTINUING DATA VERIFIED:					
** FOREIGN APPLICATIONS VERIFIED: UNITED KINGDOM 0104598.8 02/23/2001					
PG-PUB		DO NOT PUBLISH <input type="checkbox"/>		RESCIND <input type="checkbox"/>	
Foreign priority claimed <input type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 conditions met <input type="checkbox"/> yes <input type="checkbox"/> no Verified and Acknowledged Examiners's initials				ATTORNEY DOCKET NO YAMAP0800US	
TITLE : Method of growing a semiconductor multi-layer structure					

U.S. DEPT. OF COMM./PAT. & TM-PTO-436L (Rev. 12-94)

NOTICE OF ALLOWANCE MAILED		Assistant Examiner		CLAIMS ALLOWED	
				Total Claims	Print Claim for O.G.
ISSUE FEE		Primary Examiner		DRAWING	
Amount Due	Date Paid			Sheets Drwg.	Figs. Drwg.
<input type="checkbox"/> TERMINAL DISCLAIMER		PREPARED FOR ISSUE		Application Examiner	
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